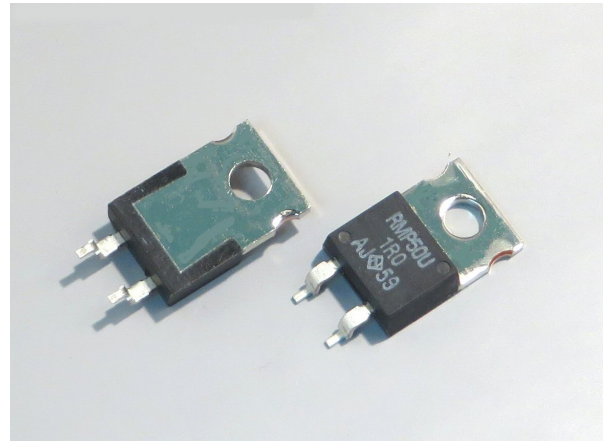


TO220 50W HIGH POWER RESISTORS

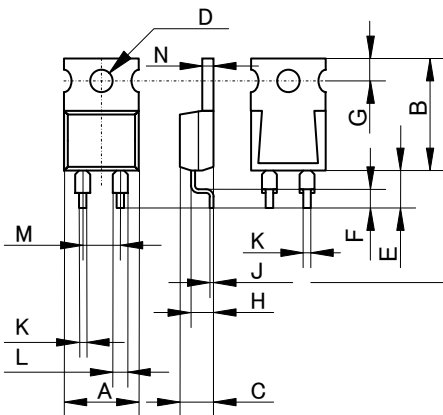
RMP-50U



Features and Applications

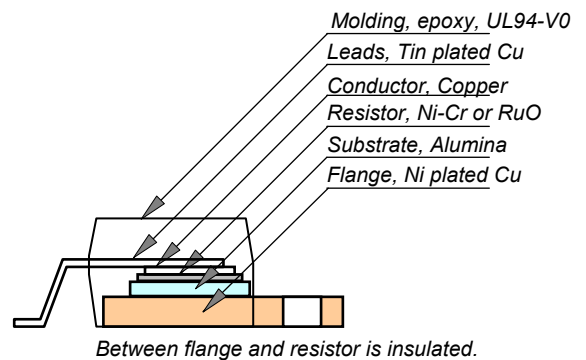
50W high power resistors in TO220 style mold package for and screw mount.  
 Non-inductive design suits high frequency applications and high-speed pulse circuits.  
 Low, 2.3 deg °C/W heat resistance from resistor hot spot to flange and long life performance are presented with thin film metallization technology and rejection of plastic adhesive joint.  
 Wide 20 milli Ohm to 510kOhm resistance range, non-inductive impedance characteristic and heat conduction through the insulated metal flange aids circuit designers.  
 Small size and thin profile suit high-density compact installations.  
 Complete thermal conduction, heat dissipation design and vibration durable design also available.  
 Applications include snubber, gate control, bleeder, filter, rush current protection, braking resistors of automotive, rail traction, wind turbine, PV, UPS and motor control inverters.

Dimensional Specifications (mm)



RMP-50U		
	mm	+/-mm
A	10.1	+/-0.2
B	15.0	+/-0.2
C	4.5	+/-0.2
D	3.6	+/-0.1
E	5.0	+/-1.0
F	2.5	+/-0.5
G	3.0	+/-0.2
H	2.75	+/-0.2
J	0.5	+/-0.05
K	0.75	+/-0.05
L	1.5	+/-0.05
M	5.08	+/-0.10
N	1.5	+/-0.05

Structure and Materials



Ordering Information

RMP-50U	C	10R0 (*)	F	Z01	Note
RMP-50U	H (>250ppm) A (100ppm) C (50ppm)	R02-R09 (+E6) R10-510K(+E24) 10R-51K (+E24)	J(5%) F(1%), J(5%) F(1%)	Z01 Z03 Z05 *	Tape reel/500pcs Tube/50pcs Tray/100pcs

\* TO263 type resistor packaging Z05 (tray) has a risk of lose of flatness, co-planarity.

Resistance value (\*) is available following modified E24, +E24.

1.0	1.1	1.2	1.3	1.5	1.6	1.8	2.0	2.2	2.4	2.5	2.7	3.0	3.3
3.6	3.9	4.0	4.3	4.7	5.0	5.1	5.6	6.2	6.8	7.5	8.0	8.2	9.1

Note\*: When ordering, additional ohm resistance notation is recommended for keeping out of misunderstanding.

TO220 50W HIGH POWER RESISTORS

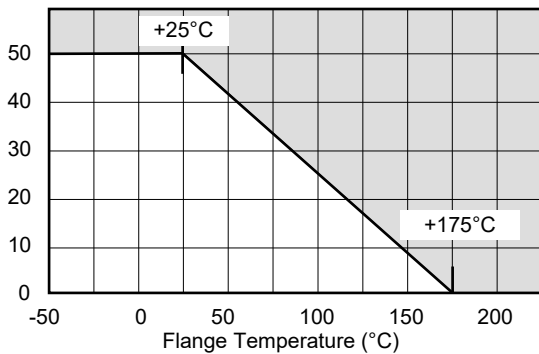
RMP-50U

Specifications

		RMP-50U		Test Conditions
Rated Power		50 Watt		-55 °C to 25 °C flange temperature
Rating Power		1 Watt		Free air.
Heat Resistance		2.3 °C/W		Hot spot to flange
Resistance Range	0.02-0.09 Ω	0.1-510KΩ	10-51K Ω	Note 2
Nominal Resistance	E6	E24+	E24	Include 2.5, 4.0, 5.0, 8.0 and 16
TCR, ppm/deg C	250(H)	100 (A)	50 (C)	Note 3
Tolerance	5%(J)	1% (F), 5% (J)	+/-1% (F)	1% tolerance at 0.01-0.091 ohm is available optionally.
Resistor Material	Thick Film		Thin Film	
Capacitance		1.69pF		Equivalent parallel capacitance.
Inductance		9.65nH		Equivalent series inductance
Category Temp.		-55 °C to +175 °C		
Max. Element Volt.		smaller either 700V or $\sqrt{P \times R}$		P is rating power and R resistance
Voltage Proof		2000VAC		Terminal and flange, 60 seconds, 1mA
Load Life		+/- 1.0 %		25 °C, 90 min. ON, 30 min. OFF, 1000 hours.
Humidity		+/- 1.0 %		40 °C, 90-95%RH, DC 0.1W, 1000 hours.
Temp. Cycle		+/- 0.25 %		-55 °C, 30 min., +155 deg C, 30 min., 5cycles
Soldering Heat		+/- 0.1 %		350+/-5 °C, 3seconds.
Solder ability		Over 95% of surface		245+/-5 °C, 3seconds.
Insulation Resistance		Over 1,000 Meg ohm		Between terminals and flange.
Vibration		+/- 0.25 %		IEC60068-2-6, see note 4
Weight		2.1 grams		

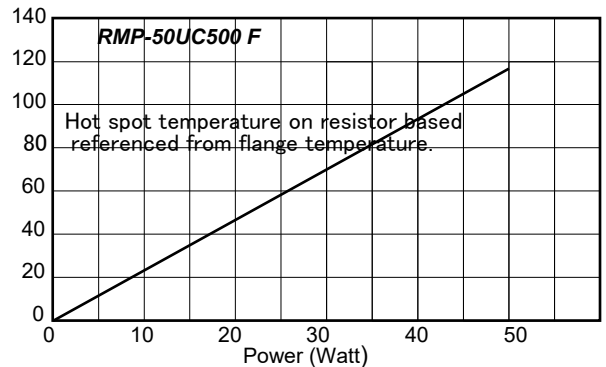
Derating

Rating Power (W)



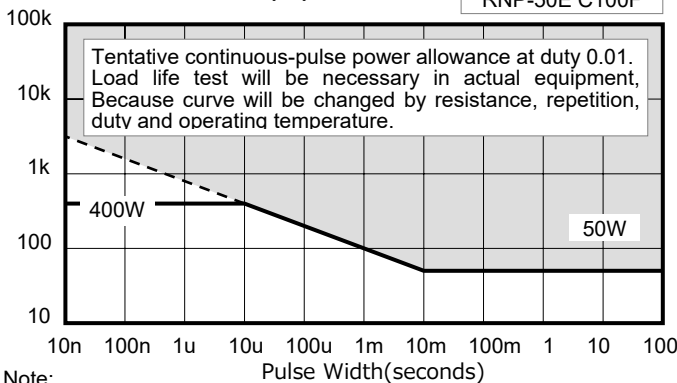
Temperature Rise

Temperature Rise (deg C)



Pulse Durability

Pulse Peak Power(W)



Note:

- (1) Insulation material is unnecessary between flange and heat-sink, flange and resistor is separated by alumina substrate.
- (2) Resistance measurement shall be made at a point 5.27mm +/-0.6 mm from the resistor body.
- (3) TCR of low resistance will be increased as 300ppm/0.02ohm, 200ppm/0.05ohm, 140ppm/0.1ohm and 80ppm/0.2ohm typically. Testing point is at 5.27mm from bottom of molding of terminals.
- (4) Test method is IEC60068-2-6, and specification is sine sweep wave form, 100Hz-2000Hz, 10 cycles, amplitude 0.75mm or 100m/s<sup>2</sup>, 90minutes. direction x-y z, Amplitude 0.75mm will be applied under break point Frequency (about 60Hz) and 100m/ s<sup>2</sup> over break point

Frequency Characteristics

Impedance (ohm)

